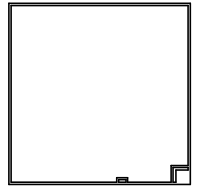
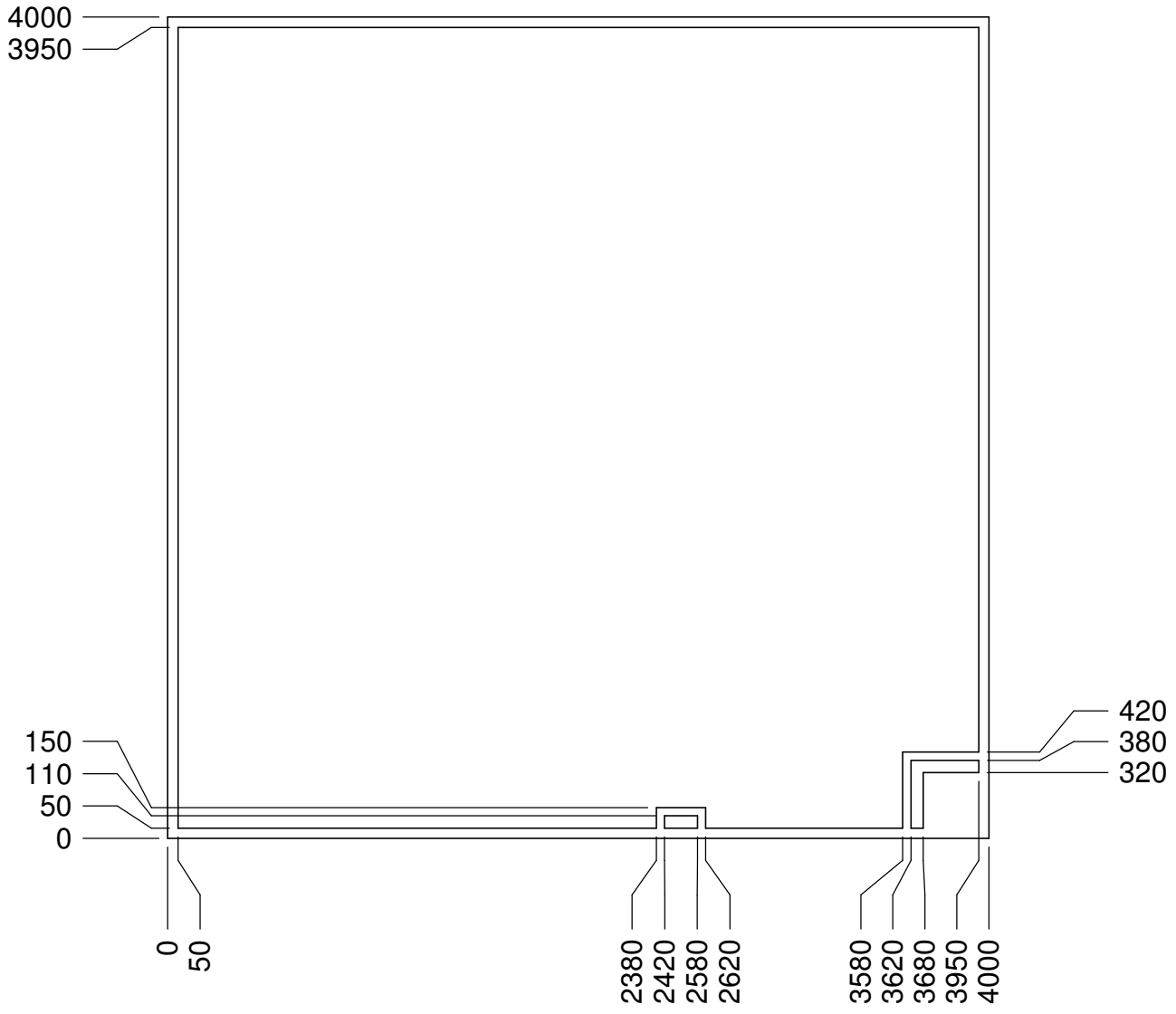


REVISIONS				
DATE	REV.	ECO	DESCRIPTION	APPROVED



SCALE 6:1

- Notes: (Unless Otherwise Specified).
- 1) DIE MATERIAL IS SILICON.
 - 2) DIE THICKNESS IS 250 μm (10 MIL).
 - 3) METALLIZATION 1.0 μm ALUMINUM (Al) OVER 0.75 μm SiO₂.
 - 4) DIE IS WITHOUT PASSIVATION.
 - 5) WIRE BONDABLE WITH GOLD (Au) OR ALUMINUM (Al) WIRE.
 - 6) DIFFERENTIAL PAIR (2 PADS) WITH LARGE GROUND PAD.
 - 7) RF / MICROWAVE PARASITIC TEST APPLICATIONS.
 - 8) TOLERANCE = $\pm 1 \mu\text{m}$.

DIMENSIONS IN MICRONS
1000 μm = 1.0mm

PART NUMBER SYSTEM						
TD	-	2	-	4.0	-	DIF
SILICON TEST DIE		BOND PADS		DIE SIZE (mm)		DIFFERENTIAL PAIR

TOLERANCE UNLESS NOTED		APPROVALS	DATE				
X.XX	+/- 0.01	DRAWN J. HINES	5/8/2010	TITLE Si TEST DIE TD SERIES			
X.XXX	+/- 0.005						
X.XXXX	+/- 0.0005						
ANGLES	+/- 0.5°	ENG		SCALE 30:1 SIZE A DRAWING NO. 154002 REV A			
ALL DIMENSIONS IN <input checked="" type="checkbox"/> INCHES <input type="checkbox"/> MILLIMETERS		MFG					
THIRD ANGLE PROJECTION		QA					
		CUST		DO NOT SCALE DRAWING SHEET 1 OF 1			
		REVISED					